











TPS65182, TPS65182B

SLVSAA2D - MARCH 2010 - REVISED JANUARY 2016

TPS65182x PMIC For E Ink® Vizplex™-Enabled Electronic Paper Display

Features

- Single Chip Power Management Solution for E Ink® Vizplex™ Electronic Paper Displays
- Generates Positive and Negative Gate and Source Driver Voltages and Back-Plane Bias from a Single, Low-Voltage Input Supply
- 3-V to 6-V Input Voltage Range
- Boost Converter for Positive Rail Base
- Inverting Buck-Boost Converter for Negative Rail
- Two Adjustable LDOs for Source Driver Supply
 - LDO1: 15 V, 120 mA (VPOS)
 - LDO2: –15 V, 120 mA (VNEG)
- Accurate Output Voltage Tracking
 - VPOS VNEG = ±50 mV
- Two Charge Pumps for Gate Driver Supply
 - CP1: 22 V, 10 mA (VDDH)
 - CP2: –20 V, 12 mA, (VEE)
- Adjustable VCOM Driver for Accurate Panel-**Backplane Biasing**
 - -0.3 V to -2.5 V
 - Adjustable Through External Potentiometer
 - 15-mA Max Integrated Switch
- Thermistor Monitoring
 - 10°C to 85°C Temperature Range
 - ±1°C Accuracy from 0°C to 50°C
- I²C Serial Interface
 - Slave Address 0x48h (1001000)
- Flexible Power-Up Sequencing

- Sleep Mode Support
- Thermally Enhanced Package for Efficient Heat Management $(48-Pin 7 mm \times 7 mm \times 0.9 mm VQFN)$

2 Applications

- Power Supply for Active Matrix E Ink Vizplex
- E-Book Readers
- EPSON® S1D13522 (ISIS) Timing Controller
- EPSON S1D13521 (Broadsheet) Timing Controller
- Application Processors With Integrated or Software Timing Controller (OMAP™)

3 Description

The TPS65182x device is a single-chip power supplies designed to for E Ink Vizplex displays used in portable e-reader applications and support panel sizes up to 9.7 inches. Two high efficiency DC/DC boost converters generate ±17-V rails which are boosted to 22 V and -20 V by two change pumps to provide the gate driver supply for the Vizplex panel.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS65182 ⁽²⁾	\(\OEN (48\)	7.00
TPS65182B	VQFN (48)	7.00 mm × 7.00 mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) Not recommended for new design.

Typical Application Schematic

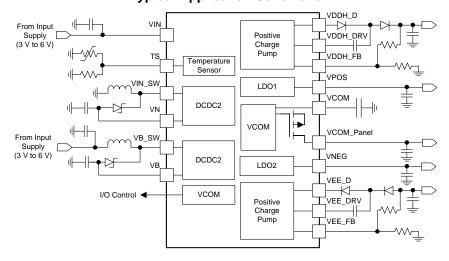




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (October 2010) to Revision D

Page

Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.



5 Description (continued)

Two tracking LDOs create the ±15-V source driver supplies which support up to 120-mA of output current. All rails are adjustable through the I²C interface to accommodate specific panel requirements.

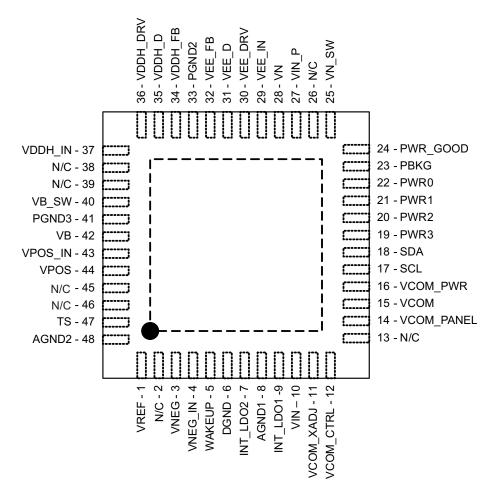
Accurate back-plane biasing is provided by a linear amplifier and can be adjusted either by an external resistor or the I²C interface. The VCOM driver can source or sink current depending on panel condition.

The TPS65182x provides precise temperature measurement function to monitor the panel temperature during operation. The temperature reading is updated every 60 s and can be accessed through the I²C interface.



6 Pin Configuration and Functions

RGZ Package 48-Pin VQFN With Exposed Thermal Pad Top View



Pin Functions

	PIN		DESCRIPTION ⁽¹⁾	
NO.	NAME	I/O	DESCRIPTION	
1	VREF	0	Filter pin for 2.25-V internal reference to ADC	
2	N/C	_	connected	
3	VNEG	0	Negative supply output pin for panel source drivers	
4	VNEG_IN	I	Input pin for LDO2 (VNEG)	
5	WAKEUP	I	Wake up pin (active high). Pull this pin high to wake up from sleep mode.	
6	DGND	_	Digital ground	
7	INT_LDO2	0	Internal supply (digital circuitry) filter pin	
8	AGND1	_	Analog ground for general analog circuitry	
9	INT_LDO1	0	Internal supply (analog circuitry) filter pin	
10	VIN	I	Input power supply to general circuitry	
11	VCOM_XADJ	I	Analog input for conventional VCOM setup method. Tie this pin to ground if VCOM is set through I ² C interface.	

There will be 0-ns, 93.75-µs, 62.52-µs of deglitch for PWRx, WAKEUP, and VCOM_CTRL, respectively.

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Pin Functions (continued)

	PIN		(1)		
NO.	NAME	1/0	DESCRIPTION ⁽¹⁾		
12	VCOM_CTRL	ı	VCOM_PANEL gate driver enable (active high)		
13	N/C	_	Not connected		
14	VCOM_PANEL	0	Panel common-voltage output pin		
15	VCOM	0	Filter pin for panel common-voltage driver		
16	VCOM_PWR	1	Internal supply input pin to VCOM buffer. Connect to the output of DCDC2.		
17	SCL	1	Serial interface (I ² C) clock input		
18	SDA	I/O	Serial interface (I ² C) data input/output		
19	PWR3	I	Enable pin for CP1 (VDDH) (active high)		
20	PWR2	I	Enable pin for LDO1 (VPOS) (active high)		
21	PWR1	I	Enable pin for CP2 (VEE) (active high)		
22	PWR0	1	Enable pin for LDO2 (VNEG) and VCOM (active high)		
24	PWR_GOOD	0	Open drain power good output pin (active low)		
25	VN_SW	0	Inverting buck-boost converter switch out (DCDC2)		
26	N/C	_	Not connected		
27	VIN_P	I	Input power supply to inverting buck-boost converter (DCDC2)		
28	VN	I	Feedback pin for inverting buck-boost converter (DCDC2)		
29	VEE_IN	I	Input supply pin for CP1 (VEE)		
30	VEE_DRV	0	Driver output pin for negative charge pump (CP2)		
31	VEE_D	0	Base voltage output pin for negative charge pump (CP2)		
32	VEE_FB	I	Feedback pin for negative charge pump (CP2)		
33	PGND2	_	Power ground for CP1 (VDDH) and CP2 (VEE) charge pumps		
34	VDDH_FB	I	Feedback pin for positive charge pump (CP1)		
35	VDDH_D	0	Base voltage output pin for positive charge pump (CP1)		
36	VDDH_DRV	0	Driver output pin for positive charge pump (CP1)		
37	VDDH_IN	I	Input supply pin for positive charge pump (CP1)		
38	N/C	_	Not connected		
39	N/C	_	Not connected		
40	VB_SW	0	Boost converter switch out (DCDC1)		
41	PGND3	_	Power ground for DCDC1		
42	VB	I	Feedback pin for boost converter (DCDC1)		
43	VPOS_IN	I	Input pin for LDO1 (VPOS)		
44	VPOS	0	Positive supply output pin for panel source drivers		
45	N/C	_	Not connected		
46	N/C	_	Not connected		
47	TS	1	Thermistor input pin. Connect a 10k NTC thermistor and a 43k linearization resistor between this pin and AGND2.		
48	AGND2	_	Reference point to external thermistor and linearization resistor		
23	PowerPad (PBKG)	_	Die substrate/thermal pad. Connect to VN with short, wide trace. Wide copper trace will improve heat dissipation. PowerPad must not be connected to ground.		

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)

	MIN	MAX	UNIT
Input voltage range at VIN, VINP	-0.3	7	V
Ground pins to system ground	-0.3	0.3	V
Voltage range at SDA, SCL, WAKEUP, PWR3, PWR2, PWR1, PWR0, VCOM_CTRL, VDDH_FB, VEE_FB, PWR_GOOD	-0.3	3.6	V
VCOM_XADJ	-3.6	0.3	V
Voltage on VB, VB_SW, VPOS_IN, VDDH_IN	-0.3	20	V
Voltage on VN, VNEG_IN, VEE_IN, VCOM_PWR	-20	0.3	V
Voltage from VINP to VN_SW	-0.3	30	V
Peak output current		Internally limited	mA
Continuous total power dissipation		2	W
T _J Operating junction temperature	-10	125	°C
T _A Operating ambient temperature (3)	-10	85	°C
T _{stg} Storage temperature	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
	Input voltage range at VIN, VINP	3	3.7	6	V
	Voltage range at SDA, SCL, WAKEUP, PWR3, PWR2, PWR1, PWR0, VCOM_CTRL, VDDH_FB, VEE_FB, VCOM_XADJ, PWR_GOOD	0		3.6	V
T _A	Operating ambient temperature	-10		85	°C
T_{J}	Operating junction temperature	-10		125	°C

⁽²⁾ All voltage values are with respect to network ground terminal.

⁽³⁾ It is recommended that copper plane in proper size on board be in contact with die thermal pad to dissipate heat efficiently. Thermal pad is electrically connected to PBKG, which is supposed to be tied to the output of buck-boost converter. Thus wide copper trace in the buck-boost output will help heat dissipated efficiently.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

		TPS65182x	
	THERMAL METRIC ⁽¹⁾	RGZ (VQFN)	UNIT
		48 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance (2)	30.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	16.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	7.1	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.2	°C/W
ΨЈВ	Junction-to-board characterization parameter	7.1	°C/W
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	_	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

 V_{IN} = 3.7 V, T_A = -10°C to 85°C, Typical values are at T_A = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT VOI	TAGE					
V _{IN}	Input voltage range		3	3.7	6	V
V _{UVLO}	Undervoltage lockout threshold	V _{IN} falling		2.9		V
V _{HYS}	Undervoltage lockout hysteresis	V _{IN} rising		400		mV
INPUT CUI	RRENT	1 11 11				
IQ	Operating quiescent current into VIN	Device switching, no load		5.5		mA
I _{STD}	Operating quiescent current into VIN	Device in standby mode		130		μA
I _{SLEEP}	Shutdown current	Device in sleep mode		2.8	10	μA
	SUPPLIES					
VI _{NT_LDO1}	Internal supply			2.7		V
V _{INT_LDO2}	Internal supply			2.7		V
V_{REF}	Internal supply			2.25		V
DCDC1 (PC	OSITIVE BOOST REGULATOR)					
V _{IN}	Input voltage range		3	3.7	6	V
	Output voltage range			17		V
V _{OUT}	DC set tolerance		-5%		5%	
I _{OUT}	Output current				160	mA
R _{DS(ON)}	MOSFET on resistance	V _{IN} = 3.7 V		350		mΩ
	Switch current limit			1.5		Α
I _{LIMIT}	Switch current accuracy		-30%		30%	
f _{SW}	Switching frequency			1		MHz
L	Inductor			2.2		μH
С	Capacitor			2x4.7		μF
ESR	Capacitor ESR			20		mΩ
DCDC2 (IN	VERTING BUCK-BOOST REGULATO	R)				
V _{IN}	Input voltage range		3	3.7	6	V
V	Output voltage range			-17		V
V _{OUT}	DC set tolerance		-5%	350 1.5 1 2.2 2x4.7 20	5%	
I _{OUT}	Output current				160	mA
R _{DS(ON)}	MOSFET on resistance	V _{IN} = 3.7 V		350		mΩ
	Switch current limit			1.5		Α
I _{LIMIT}	Switch current accuracy		-30%		30%	

⁽²⁾ Estimated when mounted on high K JEDEC board per JESD 51-7 with thickness of 1.6 mm, 4 layers, size of 76.2 mm X 114.3 mm, and 2 oz. copper for top and bottom plane. Actual thermal impedance will depend on PCB used in the application.



Electrical Characteristics (continued)

 $V_{IN} = 3.7 \text{ V}$, $T_A = -10^{\circ}\text{C}$ to 85°C, Typical values are at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L	Inductor			4.7		μΗ
С	Capacitor			2x4.7		μF
ESR	Capacitor ESR			20		mΩ
LDO1 (VPC	OS)					
V _{POS_IN}	Input voltage range		16.15	17	17.85	V
V_{SET}	Output voltage set value	V _{IN} = 17 V	14.25	15	15.75	V
$V_{INTERVAL}$	Output voltage set resolution	V _{IN} = 17 V		250		mV
V_{POS_OUT}	Output voltage range	$V_{SET} = 15 \text{ V}, I_{LOAD} = 20 \text{ mA}$	14.85	15	15.15	٧
V_{OUTTOL}	Output tolerance	$V_{SET} = 15 \text{ V}, I_{LOAD} = 20 \text{ mA}$	-1%		1%	
$V_{DROPOUT}$	Dropout voltage	$I_{LOAD} = 120 \text{ mA}$			250	mV
$V_{LOADREG}$	Load regulation – DC	I _{LOAD} = 10% to 90%			1%	
I _{LOAD}	Load current range			120		mA
I _{LIMIT}	Output current limit		200			mA
T _{SS}	Soft start time			1		ms
С	Recommended output capacitor			4.7		μF
LDO2 (VNI	EG)					
V _{NEG_IN}	Input voltage range		-17.85	-17	-16.15	V
V_{SET}	Output voltage set value	$V_{IN} = -17 \text{ V}$	-15.75	-15	-14.25	>
$V_{INTERVAL}$	Output voltage set resolution	$V_{IN} = -17 \text{ V}$		250		mV
V _{NEG_OUT}	Output voltage range	$V_{SET} = -15 \text{ V}, I_{LOAD} = -20 \text{ mA}$	-15.15	-15	-14.85	٧
V _{OUTTOL}	Output tolerance	$V_{SET} = -15 \text{ V}, I_{LOAD} = -20 \text{ mA}$	-1%		1%	
V _{DROPOUT}	Dropout voltage	I _{LOAD} = 120 mA			250	mV
V _{LOADREG}	Load regulation – DC	I _{LOAD} = 10% to 90%			1%	
I _{LOAD}	Load current range			120		mA
I _{LIMIT}	Output current limit		200			mA
T _{SS}	Soft start time			1		ms
С	Recommended output capacitor			4.7		μF
LD01 (POS	6) AND LDO2 (VNEG) TRACKING		•			
V _{DIFF}	Difference between VPOS and VNEG	$V_{SET} = \pm 15 \text{ V},$ $I_{LOAD} = \pm 20 \text{ mA}, 0^{\circ}\text{C to } 60^{\circ}\text{C}$	-50		50	mV
VCOM DRI	VER		_			
V_{COM}	Output voltage range		-2.5		-0.3	V
G	V_{COM} gain (V_{COM_XADJ}/V_{COM})	$V_{COM_ADJ} = 0 V$		1		V/V
VCOM SW	ITCH					
T _{ON}	Switch ON time	$V_{COM} = -1.25 \text{ V}, V_{COM_PANEL} = 0 \text{ V}$ $C_{VCOM} = 4.7 \mu\text{F}, C_{VCOM_PANEL} = 4.7 \mu\text{F}$			1	ms
R _{DS(ON)}	MOSFET ON resistance	$V_{COM} = -1.25 \text{ V}, I_{COM} = 30 \text{ mA}$		20	35	Ω
I _{LIMIT}	MOSFET current limit	Not tested in production		200		mA
I _{SWLEAK}	Switch leakage current	$V_{COM} = 0 \text{ V},$ $V_{COM_PANEL} = -2.5 \text{ V}$			8.3	nA
CP1 (VDDI	H) CHARGE PUMP	•	•		•	
V _{DDH_IN}	Input voltage range		16.15	17	17.85	V
	Feedback voltage			1		V
V_{FB}	Accuracy		-3%		3%	
V _{DDH_OUT}	Output voltage range	V _{SET} = 22 V, I _{LOAD} = 2 mA	21	22	23	V
	~	-				
I _{LOAD}	Load current range				10	mΑ

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Electrical Characteristics (continued)

 V_{IN} = 3.7 V, T_A = -10°C to 85°C, Typical values are at T_A = 25°C (unless otherwise noted)

IIN -	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
C _D	Recommended driver capacitor			10		nF
Co	Recommended output capacitor			4.7		μF
CP2 (VEE)	NEGATIVE CHARGE PUMP					•
V _{EE_IN}	Input voltage range		-17.75	-17	-16.15	V
	Feedback voltage			-1		V
V_{FB}	Accuracy		-3%		3%	
V _{EE_OUT}	Output voltage range	$V_{SET} = -20 \text{ V}, I_{LOAD} = 3 \text{ mA}$	-21	-20	-19	V
I_{LOAD}	Load current range				12	mA
f _{SW}	Switching frequency			560		KHz
C _D	Recommended driver capacitor			10		nF
Co	Recommended output capacitor			4.7		μF
THERMIST	OR MONITOR ⁽¹⁾					
A _{TMS}	Temperature to voltage ratio	Not tested in production		-0.0158		V/°C
Offset _{TMS}	Offset	Temperature = 0°C		1.575		V
V _{TMS_HOT}	Temp hot trip voltage (T = 50°C)	TEMP_HOT_SET = 0x8C		0.768		V
V _{TMS_COOL}	Temp hot escape voltage (T = 45°C)	TEMP_COOL_SET = 0x82		0.845		V
V_{TMS_MAX}	Maximum input level			2.25		V
R _{NTC_PU}	Internal pull up resistor			7.307		ΚΩ
R _{LINEAR}	External linearization resistor			43		ΚΩ
ADC _{RES}	ADC resolution	Not tested in production, 1 bit		16.1		mV
ADC _{DEL}	ADC conversion time	Not tested in production		19		μs
TMST _{TOL}	Accuracy	Not tested in production	-1		1	LSB
LOGIC LEV	ELS AND TIMING CHARTERISTICS (SCL, SDA, PWR_GOOD, PWRx, WAKEL	JP)		•	
V _{OL}	Output low threshold level	I _O = 3 mA, sink current (SDA, PWR_GOOD)			0.4	V
V_{IL}	Input low threshold level				0.4	V
V _{IH}	Input high threshold level		1.2			V
I _(bias)	Input bias current	V _{IO} = 1.8 V			1	μA
t _{low,WAKEUP}	WAKEUP low time	minimum low time for WAKEUP pin	150			ms
f _{SCL}	SCL clock frequency				400	KHz
OSCILLATO	OR					
f _{OSC}	Oscillator frequency			9		MHz
	Frequency accuracy	$T_A = -40$ °C to 85°C	-10%		10%	
THERMAL	SHUTDOWN		· 		<u> </u>	
T _{SHTDWN}	Thermal trip point			150		°C
	Thermal hysteresis			20		°C

^{(1) 10-}KΩ Murata NCP18XH103F03RB thermistor (1%) in parallel with a linearization resistor (43 KΩ, 1%) are used at TS pin for panel temperature measurement.

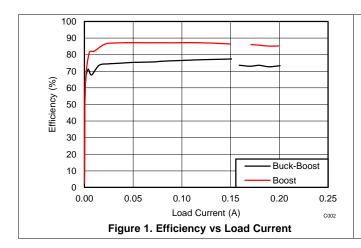


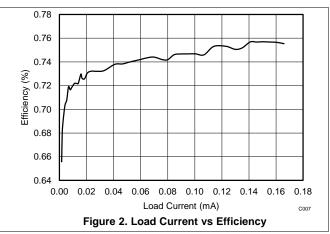
7.6 Data Transmission Timing

 $V_{BAT} = 3.6 \text{ V} \pm 5\%$, $T_A = 25^{\circ}\text{C}$, $C_L = 100 \text{ pF}$ (unless otherwise noted)

			MIN	NOM	MAX	UNIT
f _(SCL)	Serial clock frequency		100		400	KHz
	Hold time (repeated) START condition. After this	SCL = 100 KHz	4			μs
t _{HD;STA}	period, the first clock pulse is generated.	SCL = 400 KHz	600			ns
tı ow	LOW region of the COL shade	SCL = 100 KHz	4.7			
t _{LOW}	LOW period of the SCL clock	SCL = 400 KHz	1.3			μs
	LUCII period of the CCI plant.	SCL = 100 KHz	4			μs
t _{HIGH}	HIGH period of the SCL clock	SCL = 400 KHz	600			ns
	Cat we time for a remarked CTART and dition	SCL = 100 KHz	4.7			μs
t _{SU;STA}	Set-up time for a repeated START condition	SCL = 400 KHz	600			ns
t _{HD;DAT}	Data hold time	SCL = 100 KHz	0		3.45	μs
		SCL = 400 KHz	0		900	ns
	Data set-up time	SCL = 100 KHz	250			
t _{SU;DAT}		SCL = 400 KHz	100			ns
		SCL = 100 KHz			1000	
t _r	Rise time of both SDA and SCL signals	SCL = 400 KHz		4 600 4.7 1.3 4 600 0 4.7 600 0 0 250 100 1 4 600 4.7 1.3 n/a 0	300	ns
	Fall time of both CDA and CCI simple	SCL = 100 KHz			300	
t _f	Fall time of both SDA and SCL signals	SCL = 400 KHz		100 400 4 600 4.7 1.3 4 600 4.7 600 0 3.45 0 900 250 100 1000 300 300 4 600 4.7 1.3 n/a n/a	ns	
	Cat we time for CTOD and dition	SCL = 100 KHz	4			μs
t _{SU;STO}	Set-up time for STOP condition	SCL = 400 KHz	600			ns
	Due Free Time Between Other and Other Oracliffe	SCL = 100 KHz	4.7			
t _{BUF}	Bus Free Time Between Stop and Start Condition	SCL = 400 KHz	1.3			μs
	Pulse width of spikes which mst be suppressed	SCL = 100 KHz	n/a		n/a	
t _{SP}	by the input filter	SCL = 400 KHz	0		50	ns
0	Consisting lead for each has line	SCL = 100 KHz			400	
C _b	Capacitive load for each bus line	SCL = 400 KHz			400	pF

7.7 Typical Characteristics





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8 Detailed Description

8.1 Overview

The TPS65182x family of devices provides two adjustable LDOs, inverting buck-boost converter, boost converter, thermistor monitoring, and flexible power-up and power-down sequencing. The system can be supplied by a regulated input voltage ranging from 3 V to 6 V. The device is characterized across a -10°C to 85°C temperature range, best suited for personal electronic applications.

The I₂C interface provides comprehensive features for using the TPS65182x family of devices. All rails can be enabled or disabled. Power-up and power-down sequences can also be programmed through the I₂C interface, as well as thermistor and interrupt configurations. Voltage adjustment can also be controlled through the I₂C interface.

The adjustable LDOs can supply up to 120 mA of current. The default output voltages for each LDO can be adjusted through the I₂C interface. LDO1 (VPOS) and LDO2 (VNEG) track each other in a way that they are of opposite sign, but same magnitude. The sum of VLDO1 and VLOD2 is guaranteed to be less than 50 mv.

There are two charge pumps: VDDH and VEE 10 mA and 12 mA respectively. These charge pumps boost the DC-DC boost converters ±16-V rails to provide a gate channel supply. The power good functionality is open-drain output, if any of the four power rails (CP1, CP2, LDO1, LDO2) are not in regulation, encounters a fault, or is disabled, the pin is pulled low. PWR GOOD remains low if one of the rails is not enabled by the host, and only after all rails are in regulation, PWR GOOD is released to HiZ state (pulled up by external resistor).

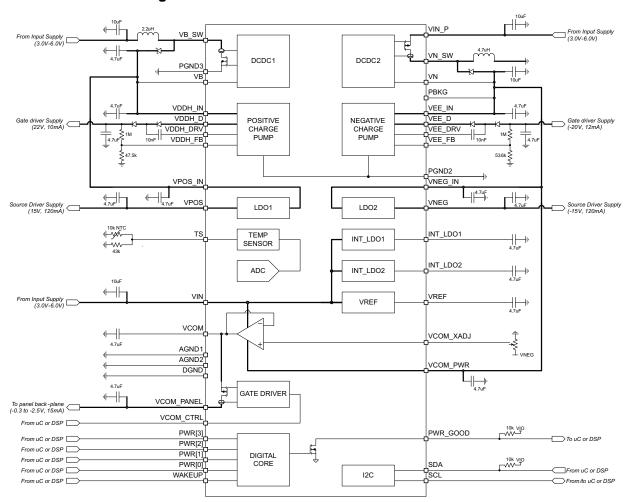
The TPS65182x family of devices provides circuitry to bias and measure an external NTC to monitor the display panel temperature in a range from -10°C to 85°C with an accuracy of ±1°C from 0°C to 50°C. Temperature measurements are triggered by the controlling host and the last temperature reading is always stored in the TMST VALUE register. Interrupts are issued when the temperature exceeds the programmable HOT, or drops below the programmable COLD threshold, or when the temperature has changed by more than a user-defined threshold from the baseline value.

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Product Folder Links: TPS65182 TPS65182B



8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Modes of Operation

The TPS65182x has three modes of operation, SLEEP, STANDBY, and ACTIVE. SLEEP mode is the lowest-power mode in which all internal circuitry is turned off. In STANDBY, all power rails are shut down but the device is ready to accept commands through PWR[3:0] pins and/or I²C interface. In ACTIVE mode one or more power rails are enabled.

SLEEP

This is the lowest power mode of operation. All internal circuitry is turned off and the device does not respond to I²C communications. TPS65182x enters SLEEP mode whenever WAKEUP pin is pulled low.

STANDBY

In STANDBY all internal support circuitry is powered up and the device is ready to accept commands either through GPIO or I²C control but none of the power rails are enabled. To enter STANDBY mode the WAKEUP pin must be pulled high and all PWRx pins must be pulled low. The device also enters STANDBY mode if input under voltage lock out (UVLO), positive boost under voltage (VB_UV), or inverting buck-boost under voltage (VN_UV) is detected, or thermal shutdown occurs.

ACTIVE

The device is in ACTIVE mode when any of the output rails are enabled and no fault condition is present. This is the normal mode of operation while the device is powered up. In ACTIVE mode, a falling edge on any PWRx pin shuts down and a rising edge powers up the corresponding rail.



8.3.2 Mode Transistions

- SLEEP -> ACTIVE WAKEUP pin is pulled high (rising edge) with any PWRx pin high. Rails come up in a predefined power-up sequence.
- SLEEP -> STANDBY WAKEUP pin is pulled high (rising edge) with all PWRx pins low. Rails will remain down until one or more PWRx pin is pulled high.
- ACTIVE → SLEEP WAKEUP pin is pulled low (falling edge). Rails are shut down following the pre-defined power-down sequence.
- ACTIVE -> STANDBY WAKEUP pin is high. All PWRx pins are pulled low (falling edge). Rails shut down in the order in which PWRx pins are pulled low. In the event of thermal shut down (TSD), under voltage lock out (UVLO), positive boost or inverting buck-boost under voltage (UV), the device shuts down all rails in a pre-defined power-down sequence.
- STANDBY -> ACTIVE WAKEUP pin is high and any PWRx pin is pulled high (rising edge). Rails come up in the same order as PWRx pins are pulled high.
- **STANDBY** \rightarrow **SLEEP** WAKEUP pin is pulled low (falling edge) while none of the output rails are enabled.

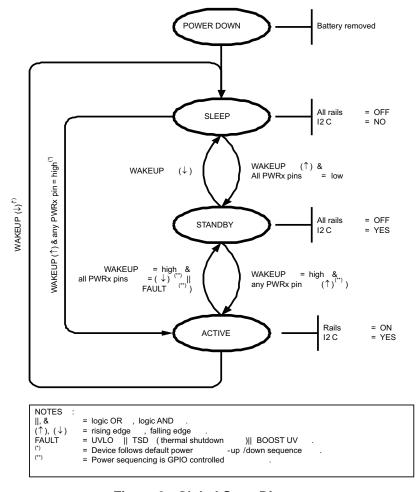


Figure 3. Global State Diagram



8.3.3 Wake-Up and Power Up Sequencing

The TPS65182x supports a default power-up sequence supporting E Ink Vizplex displays. It also offers full user control of the power-up sequence through GPIO control using the PWR3, 2, 1, 0 pins. Using GPIO control, the output rails are enabled/disabled in the order in which the PWRx pins are asserted/de-asserted, respectively, and the power-up timing is controlled by the host only. Rails are in regulation 2 ms after their respective PWRx pin has been asserted with the exception of the first rail, which takes 6 ms to power up. The additional time is needed to power up the positive and inverting buck-boost regulator which need to be turned on before any other rail can be enabled. Once all rails are enabled and in regulation the PWR_GOOD pin is released (pin status = HiZ and power good line is pulled high by external pull-up resistor). The PWRx pins are assigned to the rails as follows:

PWR0: LDO2 (VNEG) and VCOM

PWR1: CP2 (VEE)PWR3: LDO2 (VPOS)PWR4: CP1 (VDDH)

Rails are powered down whenever the host de-asserts the respective PWRx pin, and once all rails are disabled the device enters STANDBY mode. The next step is then to de-assert the WAKEUP pin to enter SLEEP mode which is the lowest-power mode of operation.

It is possible for the host to force the TPS65182x directly into SLEEP mode from ACTIVE mode by de-asserting the WAKEUP pin in which case the device follows the pre-defined power-down sequence before entering SLEEP mode.

8.3.4 Dependencies Between Rails

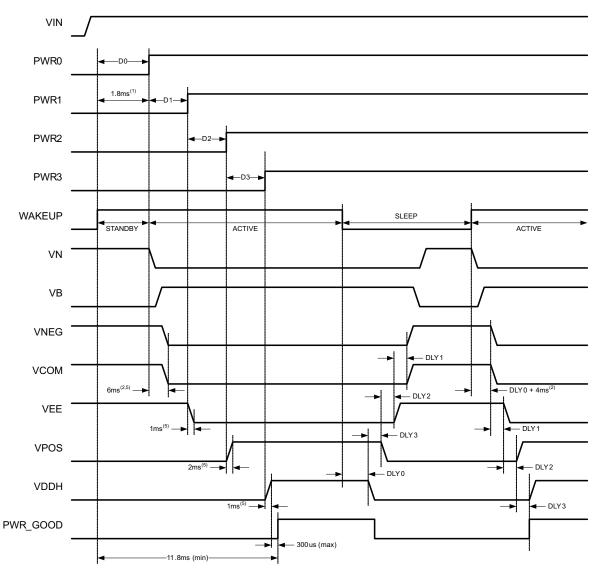
Charge pumps, LDOs, and VCOM driver are dependent on the positive and inverting buck-boost converters and several dependencies exist that affect the power-up sequencing. These dependencies are listed below.

- 1. Inverting buck-boost (DCDC2) must be in regulation before positive boost (DCDC1) can be enabled. Internally, DCDC1 enable is gated by DCDC2 power good.
- Positive boost (DCDC1) must be in regulation before LDO2 (VNEG) can be enabled. Internally LDO2 enable is gated DCDC1 power-good.
- 3. Positive boost (DCDC1) must be in regulation before VCOM can be enabled; Internally VCOM enable is gated by DCDC1 power good.
- 4. Positive boost (DCDC1) must be in regulation before negative charge pump (CP2) can be enabled. Internally CP2 enable is gated by DCDC1 power good.
- 5. Positive boost (DCDC1) must be in regulation before positive charge pump (CP1) can be enabled. Internally CP1 enable is gated by DCDC1 power good.
- 6. LDO2 must be in regulation before LDO1 can be enabled. Internally LDO1 enable is gated by LDO2 power good.
- 7. The minimum delay time between any two PWRx pins must be > 62.5 µs in order to follow the power up sequence defined by GPIO control. If any two PWRx pins are pulled up together (< 62.5 µs apart) rails will be staggered in a manner that a subsequent rail's enable is gated by PG of a preceding rail. In this case, the default order of power-up is LDO2 (VNEG), CP2 (VEE), LDO1 (VPOS), and CP1(VDDH). If any two PWRx pins are pulled low then all rails will go down at the same time.

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- (1) Minimum delay time between WAKEUP rising edge and IC rady to accept I 2C transaction.
- (2) It takes 2ms minimum for each internal boost regulator to start up before VNEG can be enabled
- (5) It takes up to 2ms for LDOs (VPOS, VNEG) and 1ms for charge pumps (VDDH, VEE), to reach their steady state after being enabled.

Figure 4. Power-Up and Power-Down Timing Diagram

8.3.5 Soft-Start

Softstart for DCDC1, DCDC2, LDO1, and LDO2 is accomplished by lowering the current limits during start-up. If DCDC1 or DCDC2 are unable to reach power-good status within 10 ms, the device enters STANDBY mode.

8.3.6 VCOM Adjustment

VCOM can be adjusted by an external potentiometer by connecting a potentiometer to the VCOM_XADJ pin. The potentiometer must be connected between ground and a negative supply. The gain from VCOM_XADJ to VCOM is 1 and therefore the voltage applied to VCOM_XADJ pin should range from -0.3 to -2.5V.

8.3.7 VPOS and VNEG Supply Tracking

LDO1 (VPOS) and LDO2 (VNEG) track each other in a way that they are of opposite sign but same magnitude. The sum of VLDO1 and VLOD2 is guaranteed to be < 50 mV.

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DLY 0-DLY 3 are power up /down delays are factory-set to 2ms



8.3.8 Fault Handling and Recovery

The TPS65182x monitors input and output voltages and die temperature and will take action if operating conditions are outside normal limits. Whenever the TPS65182x encounters:

- Thermal Shutdown (TSD)
- Positive Boost Under Voltage (VB_UV)
- Inverting Buck-Boost Under Voltage (VN_UV)
- Input Under Voltage Lock Out (UVLO)

it will shut down all power rails and enter STANDBY mode. Shut down follows the pre-defined power-down sequence and once a fault is detected, the PWR GOOD pin is pulled low.

Whenver the TPS65182x encounters under voltage on VNEG (VNEG_UV), VPOS (VPOS_UV), VEE (VEE_UV) or VDDH (VDDH_UV) it will shut down the corresponding rail (plus any dependent rail) only and remain in ACTIVE mode, allowing the DCDC converters to remain up. Again, the PWR GOOD pin will be pulled low.

As the PWRx inputs are edge sensitive, the host must toggle the PWRx pins to re-enable the rails through GPIO control, i.e. it must bring the PWRx pins low before asserting them again.

8.3.9 Power Good Pin

The power good pin (PWR_GOOD) is an open drain output that is pulled high when all four power rails (CP1, CP2, LDO1, LDO2) are in regulation and is pulled low if any of the rails encounters a fault. PWR_GOOD remains low if one of the rails is not enabled by the host and only after all rails are in regulation PWR_GOOD is released to HiZ state (pulled up by external resistor).

8.3.10 Panel Temperature Monitoring

The TPS65182x provides circuitry to bias and measure an external negative temperature coefficient resistor (NTC) to monitor device temperature in a range from -10°C to 85°C with and accuracy of ±1°C from 0°C to 50°C. Temperature reading is automatically updated every 60 s.

8.3.11 NTC Bias Circuit

Figure 5 below shows the block diagram of the NTC bias and measurement circuit. The NTC is biased from an internally generated 2.25-V reference voltage through an integrated 7.307-K Ω bias resistor. A 43-K Ω resistor is connected parallel to the NTC to linearize the temperature response curve. The circuit is designed to work with a nominal 10-K Ω NTC and achieves accuracy of ±1°C from 0°C to 50°C. The voltage drop across the NTC is digitized by a 10-bit SAR ADC and translated into an 8-bit two's complement by digital per Table 1.



Table 1. ADC Output Value vs Termperature

TEMPERATURE	TMST_VALUE[7:0]
< -10°C	1111 0110
-10°C	1111 0110
-9°C	1111 0111
-2°C	1111 1110
-1°C	1111 1111
0°C	0000 0000
1°C	0000 0001
2°C	0000 0010
25°C	0001 1001
85°C	0101 0101
> 85°C	0101 0101

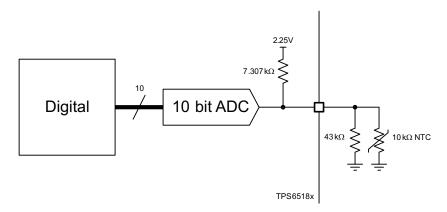


Figure 5. NTC Bias and Measurement Circuit

8.4 Device Functional Modes

8.4.1 I²C Bus Operation

The TPS65182x supports a special I²C mode making it compatible with the EPSON® Broadsheet S1D13521 timing controller. Standard I²C protocol requires the following steps to read data from a register:

- 1. Send device slave address, R/nW bit set low (write command)
- 2. Send register address
- 3. Send device slave address, R/nW set high (read command)
- 4. The slave will respond with data from the specified register address.end device slave address, R/nW set high (read command).

The EPSON® Broadsheet S1D13521 controller does not support I2C writes nor I2C reads from addressed registers, therefore the TPS65182x I²C interface has been modified and the reading the temperature data is reduced to two steps:

- 1. Send device address, R/nW set high (read command)
- 2. Read the data from the slave. The slave will respond with data from TMST VALUE register address.

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Device Functional Modes (continued)

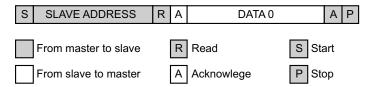


Figure 6. Subaddress in I²C Transmission

The I²C Bus is a communications link between a controller and a series of slave terminals. The link is established using a two-wired bus consisting of a serial clock signal (SCL) and a serial data signal (SDA). The serial clock is sourced from the controller in all cases where the serial data line is bi-directional for data communication between the controller and the slave terminals. Each device has an open Drain output to transmit data on the serial data line. An external pull-up resistor must be placed on the serial data line to pull the drain output high during data transmission.

Data transmission is initiated with a start bit from the controller as shown in Figure 7. The start condition is recognized when the SDA line transitions from high to low during the high portion of the SCL signal. Upon reception of a start bit, the device will receive serial data on the SDA input and check for valid address and control information. If the appropriate group and address bits are set for the device, then the device will issue an acknowledge pulse and prepare the receive subaddress data. Subaddress data is decoded and responded to as per the Register Map section of this document. Data transmission is completed by either the reception of a stop condition or the reception of the data word sent to the device. A stop condition is recognized as a low to high transition of the SDA input during the high portion of the SCL signal. All other transitions of the SDA line must occur during the low portion of the SCL signal. An acknowledge is issued after the reception of valid address, sub-address and data words. Reference Figure 7.

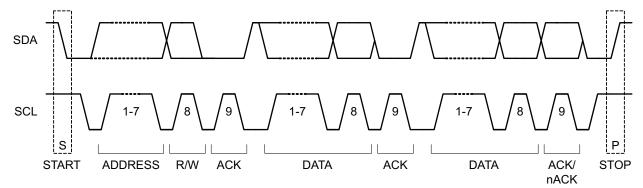


Figure 7. I²C Start/Stop/Acknowledge Protocol

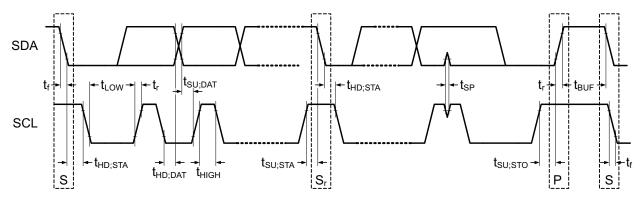


Figure 8. I²C Data Transmission Timing

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8.5 Register Maps

Table 2. Register Address Map

REGISTER	ADDRESS (HEX)	NAME	DEFAULT VALUE	DESCRIPTION		
0	0x00	TMST_VALUE	N/A	Thermistor value read by ADC		

8.5.1 Thermistor Readout (TMST_VALUE) Register (offset = 0x00h)

DATA BIT	D7	D6	D5	D4	D3	D2	D1	D0	
FIELD NAME		TMST_VALUE[7:0]							
READ/WRITE	R	R	R	R	R	R	R	R	
RESET VALUE	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	

FIELD NAME	BIT DEFINITION
	Temperature read-out
	1111 0110 – < -10°C
	1111 0110 – -10°C
	1111 0111 – -9°C
	1111 1110 – -2°C
	1111 1111 – -1 °C
TMST_VALUE[7:0]	0000 0000 – 0 °C
	0000 0001 – 1°C
	0000 0010 – 2°C
	0001 1001 – 25°C
	0101 0101 – 85°C
	0101 0101 -> 85°C

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Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS65185 device is used to power display screens in E-book applications, specifically E-lnk Vizplex display, by connecting the screen to the positive and negative charge pump, LDOs 1 and 2, and VCOM rails. The display screens size that can be supported up to 9.7 inches.

9.2 Typical Application

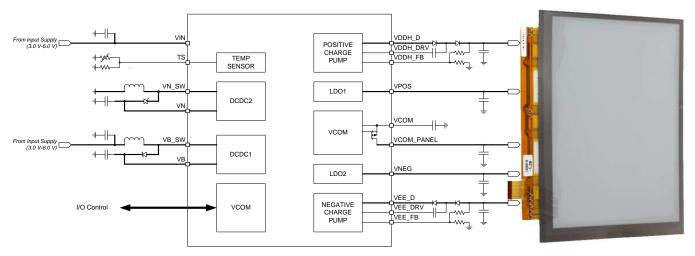


Figure 9. Typical Application Schematic

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 3 as the input parameters.

Table 3. Design Parameters

	VOLTAGE	SEQUENCE (STROBE)
VNEG (LDO2)	–15 V	1
VEE (Charge pump 2)	–20 V	2
VPOS (LDO1)	15 V	3
VDDH (Charge pump 1)	22 V	4

9.2.2 Detailed Design Procedure

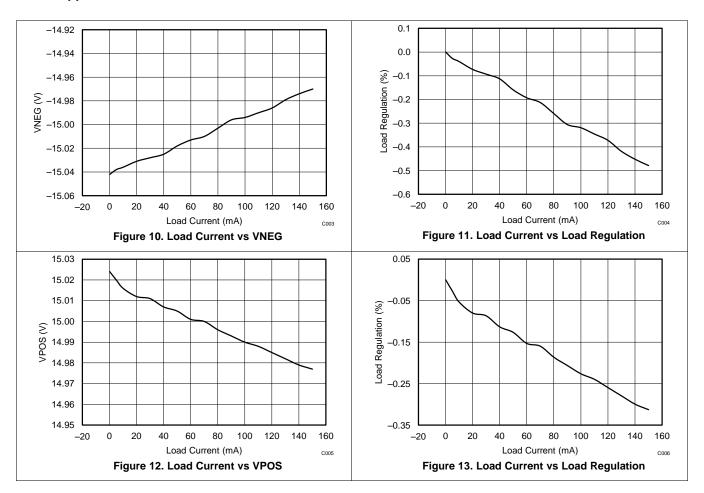
For the positive boost regulator (DCDC1) a 10-µF capacitor can be used as the input capacitor value; two 4.7-µF capacitor are used as output capacitors to reduce ESR along with a 2.2-µH inductor. For the inverting buck-boost regulator (DCDC2), an 10-µF capacitor can be used at the input capacitor value; A 10-µF and 4.7-µF capacitor are used as output capacitors to reduce ESR, with a 4.7-µH inductor. Capacitor ESR for all capacitors should be around 20 mΩ, and ceramic X5R material. These are the typical the values used, additional inductor and capacitor values can be used for improved functionality, but the parts should be rated the same as the recommended external components listed in Table 4.



Table 4. Recommended External Components

PART NUMBER	VALUE	SIZE	MANUFACTURER
INDUCTORS			
LQH44PN4R7MP0	4.7 µH	4 mm × 4 mm × 1.65 mm	Murata
NR4018T4R7M	4.7 µH	4 mm × 4 mm × 1.8 mm	Taiyo Yuden
VLS252015ET-2R2M	2.2 µH	2 mm × 2.5 mm × 1.5 mm	TDK
NR4012T2R2M	2.2 µH	4 mm × 4 mm × 1.2 mm	Taiyo Yuden
CAPACITORS			
GRM21BC81E475KA12L	4.7 μF, 25 V, X6S	805	Murata
GRM32ER71H475KA88L	4.7 μF, 50 V, X7R	1210	Murata
All other capacitors	X5R or better	_	_
DIODES			
BAS3010	_	SOD-323	Infineon
MBR130T1	_	SOD-123	ON-Semi
BAV99 —		SOT-23	Fairchild
THERMISTOR			
NCP18XH103F03RB	10 kΩ	603	Murata

9.2.3 Application Curves





10 Power Supply Recommendations

The device is designed to operate with an input voltage supply range from 3 V to 6 V. This input supply can be from a externally regulated supply. If the input supply is located more than a few inches from the TPS65185, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 10 µF is a typical choice.

11 Layout

11.1 Layout Guidelines

The layout guidelines for TPS65182x are as follows:

- PBKG (Die substrate must connect to VN (-16 V) with short, wide trace. Wide copper trace will improve heat dissipation.
- Power pad is internally connected to PBKG and must be connected to ground, but connected to VN with a short wide copper trace.
- Inductor traces must be kept on the PCB top layer free of any vias.
- Feedback traces must be routed away from any potential noise source to avoid coupling.
- Output caps must be placed immediately at output pin.
- VIN pins must be bypassed to ground with low ESR ceramic bypass capacitors.

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11.2 Layout Example

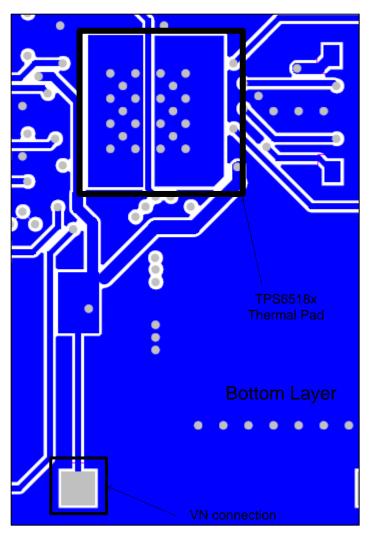


Figure 14. Typical Layout of TPS6518x



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 5. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS65182	Click here	Click here	Click here	Click here	Click here
TPS65182B	Click here	Click here	Click here	Click here	Click here

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

OMAP, E2E are trademarks of Texas Instruments.

Vizplex is a trademark of E Ink Corporation.

E Ink is a registered trademark of E Ink Corporation.

EPSON is a registered trademark of Seiko Epson Corporation.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 10-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS65182BRGZR	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-10 to 85	E INK TPS65182B
TPS65182BRGZR.B	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-10 to 85	E INK TPS65182B
TPS65182BRGZT	Active	Production	VQFN (RGZ) 48	250 SMALL T&R	Yes	NIPDAU	Level-3-260C-168 HR	-10 to 85	E INK TPS65182B
TPS65182BRGZT.B	Active	Production	VQFN (RGZ) 48	250 SMALL T&R	Yes	NIPDAU	Level-3-260C-168 HR	-10 to 85	E INK TPS65182B

⁽¹⁾ Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.



PACKAGE OPTION ADDENDUM

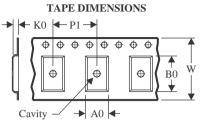
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

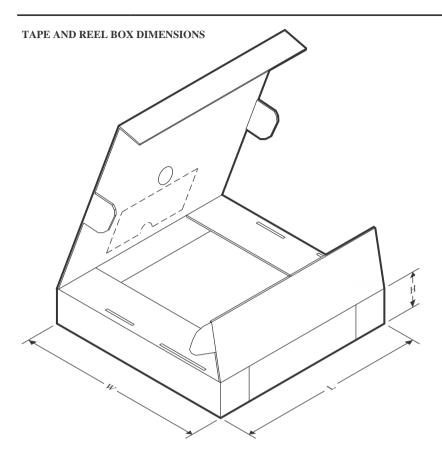
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	TPS65182BRGZR	VQFN	RGZ	48	2500	330.0	16.4	7.3	7.3	1.1	12.0	16.0	Q2
L	TPS65182BRGZT	VQFN	RGZ	48	250	180.0	16.4	7.3	7.3	1.1	12.0	16.0	Q2

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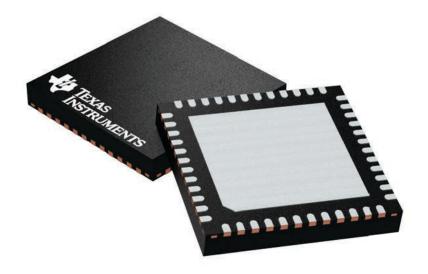


*All dimensions are nominal

Г	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	TPS65182BRGZR	VQFN	RGZ	48	2500	367.0	367.0	38.0
Г	TPS65182BRGZT	VQFN	RGZ	48	250	210.0	185.0	35.0

7 x 7, 0.5 mm pitch

PLASTIC QUADFLAT PACK- NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

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